$SERI/TP - 641 - 849$ $CONF - 800806 - -41$

- 0.2352

ANALYSIS OF THE APPLICATION THERMOGALVANIC CELLS TO THE CONVERSION OF LOW GRADE HEAT TO ELECTRICITY

)

HELENA L. CHUM R. F. FAHLSING T. S. JAYADEV

AUGUST 1980

:,p·

IMASTER

••

23348

PRESENTED AT THE 15TH INTERSOCIETY ENERGY CONVERSION ENGINEERING CONFERENCE

SEATTLE, WASHINGTON AUGUST 18-22, 1980

PREPARED UNDER TASK No. 3142

Solar Energy Research Institute

A Division of Midwest Research Institute

1617 Cole Boulevard Golden, Coiorado 80401

Prepared for the U.S. Department of Energy Contract No. EG-77-C-01-4042

DISCLAIMER

This report was prepared as an account of work sponsored by an agency of the United States Government. Neither the United States Government nor any agency Thereof, nor any of their employees, makes any warranty, express or implied, or assumes any legal liability or responsibility for the accuracy, completeness, or usefulness of any information, apparatus, product, or process disclosed, or represents that its use would not infringe privately owned rights. Reference herein to any specific commercial product, process, or service by trade name, trademark, manufacturer, or otherwise does not necessarily constitute or imply its endorsement, recommendation, or favoring by the United States Government or any agency thereof. The views and opinions of authors expressed herein do not necessarily state or reflect those of the United States Government or any agency thereof.

DISCLAIMER

Portions of this document may be illegible in electronic image products. Images are produced from the best available original document.

Printed in the United States of America Available from: National Technical Information Service U.S. Department of Commerce 5285 Port Royal Road Springfield, VA 22161 Price: Microfiche \$3.00 Printed Copy \$4. oo

...

NOTICE

This report was prepared as an account of work sponsored by the United States Government. Neither the United States nor the United States Department of Energy, nor any of their employees, nor any of their contractors, subcontractors, or their employees, makes any warranty, express or implied, or assumes any legal liability or responsibility for the accuracy, completeness or usefulness of any information, apparatus, product or process disclosed, or represents that its use would not infringe privately owned rights.

ANALYSIS OF THE APPLICATION OF THERMO-GALVANIC CELLS TO THE CONVERSION OF LOW GRADE HEAT TO ELECTRICITY

~e1ena L. Chum, R.F. Fahlsing, and T.S. Jayadev* Solar Energy Research Institute, 1617 Cole Blvd., Golden, Colorado 80401

ı

Abstract

Aqueous thermogalvanic cells, the solution analogs of solid-state thermoelectric devices, are compared for power generation. Measurements on the copper|copper formate|copper system yield thermoelectric powers,(ΔE/ΔT)_{I=O}, of 1.25 - 1.9 mV/degree,
which are higher than those exhibited by other copper systems. In these solutions three copper formate complexes are present. Practical cells were built and tested. The power output is largely limited .by cell resistance, though mass and charge transfer contribute to the observed overvoltages. The coupling of this thermogalvanic system with an electrochemical photovoltaic effect (a photothermo-
galvanic cell) is briefly described.

Nomenclature

Background

Thermogalvanic Cells

Thermogalvanic cells can be defined as galvanic cells in which the temperature is not uniform. They are the electrochemical equivalent of thermoelectric devices, which convert heat into electri-
city. In these cells two or more electrodes are at different temperatures. These electrodes, not necessarily chemically identical or reversible, are in contact with an electrolyte, solid *or* liquid, not necessarily homogeneous in composition, and with or without **penneable** membranes interposed in the electrolyte. During the passage of current

*Present Address: Energy ·Conversion Devices, 1675 West Maple Road, Troy, Michigan.

This book was prepared as an account of work sponsored by an agency of the United States Government.

Neither the United States Government nor any agency threeof, nor any of their employees, makes any

varianty, express or

through the thermogalvanic cells, matter is transferred from one electrode to the other **as a** result of the electrochemical reactions at the electrode/ electrolyte interface and ionic transport in the electrolyte. In this respect, the thermogalvanic cell differs from metallic thermocouples, or thermoelectric devices in general, in which no net transfer of material occurs, and the state of the conductor remains unchanged with the passage of current. In fact, thermoelectric effects in the metallic leads from the electrodes in the thermogalvanic cells contribute to the observed EMF of these cells.1-5

The *EMF.of* a thermogalvanic cell in its initial state arises from three factors: (1) the dif- ·ferences in e]ectrode temperature; (2) the thermal liquid junction potential; and (3) the metallic from (1) and (2) is about two orders of magnitude
larger than the EMF from (3), which arises at the junction in the external circuit between two electrode metals at different temperatures (the Seebeck effect). With the passage of time, a thermal cell is subject to thermal diffusion in the electrolyte (Soret effect), which tends to concentrate the more concentrated electrolytes in the cold region. The concentration gradient further changes the two electrode potential~. and the cell reaches a **new** stationary state (final EMF).1-5

The thennogalvanic cell can be written as M(T₁)|electrode(T₁)|Electrolyte(T₁)|Electrolyte(T₂)|
electrode(T₂)|M(T₁) where T₂>T₁. The electrodes can be metals or gases with inert electrodes. $1,2$ The electrolyte can be a solution, a fused salt, or **a** solid electrolyte. Temperature T1 is fixed **and** T2 is varied. The most **widely** used sign convention for thermogalvanic cells is that the $\tilde{EMF(E)}$ is pos-
itive when the terminal connected to the electrode itive when the terminal connected to the electrode
at T₂ is positive with respect to that connected
to the cold electrode. Therefore the hot electrode is the cathode, and the $(dE/dT_2)\tau_1$ constant is positive. This coefficient $(dE/d\bar{T})_{\text{thermal}}$ is the thermoelectric power, sometimes also designated the "Seebeck coefficient" in analogy with the nomenclature used in thermoelectric phenomena.⁶ The thermoelectric power is obtained from measurements **at** open circuit (I=O).

The thermoelectric power can be described as the sum of a heterogeneous term (due to the elec-
trode temperature effect) and a homogeneous part (thermal liquid junction potential for solutions or the thermoelectric effect on solid or liquid

RESTRIBUTION OF THIS DOCUMENT IS UNLIMITED

ionic conductors). The driving force for the thennogalvanic cell is the transport of entropy from the high temperature reservoir (at T2) to the low temperature sink (at T_1), as is the case in any heat engine.1-5

(" -•.

> For a thermogalvanic cell, for instance, with pure metal electrodes and a simple electrolyte MXn, solid or fused, the EMF of the cell is the electrical potential of a wire attached to the hot electrode minus the potential of a similar wire attached to the cold electrode. The electrical work for n equivalents of electricity is determined by the entropy absorbed from the heat reservoir surrounding the hot electrode when positive electricity passes through the cell from the cold to the
hot electrode. ⁷ This entropy is identical to the hot electrode.[/] This entropy is identical to the sum of the entropy absorbed in the electrode reaction, [in this case, SM(molal entropy of the **meta.1**)- \mathcal{S}_{M} n+(partial molar entropy of $\mathsf{M}^{\mathsf{n+}}$)-n $\mathcal{S}_{\mathsf{e}(\mathsf{M})}$ (partial molal entropy of the electron in M)] and the entropy transpor1ed **away** from the hot electrode [in this case, -SMn+(entropy of transfer of Mⁿ⁺)-nSe_(M)(entropy of transfer of e^-)].³⁻⁷ The entropies of transfer result from heat effects attributable to the movement of electrons and ions through a ther-
mal gradient under the influence of a voltage drop. Since \overline{S} + S* = \overline{S} (total transported entropy), one can **write:**

$$
nF \frac{dE}{dT} = S_M - \overline{S}_M n^+ - n\overline{S}_e^-(M)
$$
 (1)

This expression also holds for aqueous thermocells 1 after the Soret equilibrium is reached (final EMF). For the initial EMF of such aqueous thermocells (uniform electrolyte distribution) the term t_{s} (S_M_n+ $+$ nS \bar{y} -), where t_i is the transference number of the anion, must be added to that expression.

The thermoelectric power, (dE/dT) thermal mea-
sured at I=0 or calculated from the appropriate sured at I=O or calculated from the appropriate equation has been used to calculate the figure of merit, Z, of the thermogalvanic cell,⁵ in analogy to that used for thermoelectric devices⁶

$$
2 = \frac{(dE/dT)^2}{\rho \kappa} = 0 \quad \text{in } K^{-1}
$$
 (2)

where $\rho =$ specific resistivity in ohm-cm, κ is the specific thermal conductivity in Wcm $^{-1}$ K $^{-1}$, and dE/ dT is in $\texttt{V} \texttt{K}^{-1}$. Ionic conductors were found to have figures of merit of approximately 10-3K-l, which are of the order of magnitude of the thermoelectric semiconducting devices.6 The conversion efficiencies are Carnot cycle limited for both the thermoelectric and thermogalvanic cells. However, **anti**cipated practical figures of merit would be consistently less than those obtained from I•O.

The expression of Telkes⁸ for solid state device efficiencies, n, has been applied to thennogalvanic cells:

$$
\eta = \frac{1}{\frac{2 T_2}{T_2 - T_1} + \frac{4 \kappa \rho}{\left(\frac{dE}{dT}\right)^2} \left(\frac{T_2 - T_1}{T_2}\right)}
$$
(3)

where the first term in the denominator is related to the Carnot efficiency and the second is related to the figure of merit. Other expressions have been calculated for molten salt thermogalvanic
cells.9

The analyses of Z and n above do not consider
electrode polarization effects which effectively limit the power output of such devices under current drain.

Some thermogalvanic cells have been investigated for power gengration.10 Molten salts¹¹ and solid electrolytes¹² were chosen for these devices. In these media wide operating temperature ranges are possible, and therefore, large Carnot efficiencies.

In this paper we are interested in the conver-
sion of low grade heat into electricity. Examples of sources of free low grade heat are OTEC (Ocean Thermal Energy Conversion), geothermal, waste in-dustrial heat, etc .. Solar ponds are also a source of low grade heat. In this context the range of 20 - 80⁰C is of importance. Aqueous electrolytes are suitable for this temperature range. This paper reviews three types of thermogalvnic cells in aqueous media and presents new data on a copper system. A preliminary analysis of the suitability of such systems for power generation utilizing a low grade heat source will be presented at the meeting.

Aqueous Thermogalvanic Cells

Three general types of·thermogalvanic cells can be singled out:

(1) Metal electrodes inmersed in unsaturated solutions of salts, therefore two electrodes of the first kind (M/Mⁿ⁺):

$$
M(T_1)
$$
 | MA | $M(T_2)$.

Cells of this type have long been studied. 1.2 An example is $Cu|CuSO_A$ unsaturated Cu.

(2) Metal electrodes irrmersed in saturated solutions of salts, separated by a salt bridge:

$$
M(T_1) | MA(T_1, a_1) | | MA(T_2, a_2) | M(T_2).
$$

Clampitt and German 13 patented and measured some of these cells, e.g., $cu|CuSO_4$ satd. T₁ || CuSO₄ satd. T2 Cu in aqueous, aqueous acid, and non-aqueous media.

(3) Redox soluble couples with inert electrodes (E):

$$
E(T_1) | M^{m+}, M^{n+} | E(T_2).
$$

suggested by Burrows, 14 and measured for the Pt|Fe³⁺, Fe²⁺|Pt and Pt|Fe(CN)₆⁴⁻, Fe(CN)₆3-|Pt
cyclose systems.

In the first two types of thermogalvanic cells
described above, the electrodes undergo permanent changes, with anodic dissolution at one temperature, and cathodic deposition at the other. In order to

continuously produce electricity from these cells, the temperature of the electrodes has to be reversed periodically. In the second type, couples are chosen such that the solubility of MA varies widely with temperature. The activity of M^{n+} ions in each chamber is kept reasonably constant under current drain, by the precipitation or dissolution of MA, coupled to the electrode processes. There is anion transfer from one to the other side of the cell. In the third type, since the redox couple is solu-
ble, there are no permanent changes at the electrodes, and the devices can be operated continuously provided there **is a** temperature differential.

,,

The first two types can present dendrite growth at the metal electrode/electrolyte interface, which can create practical difficulties such
as short circuits. All of these cells can present as short circuits. All of these cells can present .
activation (charge transfer) and/or concentration (mass transfer) polarization in addition to ohmic polarization, which decrease the power output. For type (2) the dissolution and/or precipitation of MA can be rate limiting.

Table I compares the thennoelectric powers for examples of these three types of cells, and, when available, the power output of these systems.

TABLE I - THERMOELECTRIC POWERS FOR SOME SELECTED THERMOGALVANIC CELLS IN AQUEOUS MEDIA

*Maximum power, IR free values.

3

For type (3) the coupling of the thermogal-
vanic cell with an electrochemical photovoltaic
effect was proposed by Burrows¹⁴ for the cell (hot)n-TiO₂|Fe(CN)₆⁴⁻,|Fe(CN)₆³⁻|Pt(cold). Such cell was called photothennogalvanic. No data have been published to date.

-

In 1917, Case¹⁷ described that copper electrodes irrmersed in copper fonnate solutions, **wit~** in a certain range of acidity, displayed an electrochemical photovoltaic effect, when the anode was illuminated and the cathode kept in the dark. Alternating current was produced by reversing the illumination process, f.e., by illuminating the previously dark cathode, now anode, and keeping
the other electrode in the dark. Jayadev¹⁸ con-
firmed Case's results on the observed photoeffect. In this paper we report the preliminary results on the investigation of the copper-copper fonnate thermogalvanic system. The initial results on the coupling of the thermogalvanic cell with the electrochemical photovoltaic effect, to be called photothermogalvanic effect, are also reported.

II. Experimental Part

The discharge behavior of the thennogalvanfc cells was investigated in U-shaped cells with jacketed arms, similar to that described in reference 14. The temperature in each half cell was controlled to $\pm 0.2^\circ$ C by a continuous flow of water from two thermostated water circulators (Lauda Brinkman K/2R and Haake F-3). Cold electrode temperatures were maintained at 10 to 20°c and the hot half-cell temperature was varied between 30 and 80^oC.

Copper electrodes were made of pure copper sheets (99.9995%, Electronic Space Products, Inc.), spot welded to copper wires. The wire and the back of the electrodes were coated with Miccroflex (Miccro product) paint, resistant to the investigated solutions under the experimental conditions. Copper reference electrodes were also made of copper wires (99.9995, Electronic Space Products Inc.) protected from contact with the solution by the Mfccroflex-pafnt with the exception of the last 0.3 cm.

A sample of copper formate $(Cu(HCOO))_2 \cdot 4$ H₂O, 98%) was provided by Kocide Chemical Corporation. Reagent grade sodium fonnate (Baker), formic acid (Baker), copper sulfate pentahydrate (Mallincrodt), sodium tetrafluoroborate (Alfa), sulfuric and nitric acids (Baker) were employed. Solutions of copper salts were made up with deionized water which was previously boiled and rapidly cooled down. A plastic glove bag (I2R) under nitrogen was used for the preparation and transference of solutions. The pH of the solutions was measured with a Beckman digital pH meter no. 3560 and with Orion combination electrodes (91-02).

A potentfostat-galvanostat, Princeton Applied Research Corporation (PARC) 173 D **with** 176 current voltage converter or 376 digital coulometer was employed **as a** source of constant current or poten- tial. The digital voltmeter Keithley model 174 was employed. A conductivity bridge (Sybron-Barn-
stead, PM-70CB) was used for room temperature stead, PM-70CB) was used for room temperature
measurements. A current-interruptor technique was employed for the measurement of the **resistance** of

4

the solutions in the thennogalvanic cells.

The more practical cells tested were made of
PVC tubing (2.5 cm diameter) and variable length $(1.25$ to $\overline{5.0}$ cm). Copper electrodes were attached to the PVC with the Miccroflex paint. In these cells the temperature at each electrode was maintained through a copper heat-exchanger with a copper plate (7 cm diameter) which was soldered to copper tubing in the back. Water from the thermostated circulators flowed through the tubing.

Temperatures were measured with a Bailey Instruments digital thennometer BAT-9 with microprobes (ICT-4) or copper-constantan thermocouples.

A slide projector with a tungsten light source (300 W bulb) was used for illuminating the eleced and the intensity of the radiation was measured with a thermopile (The Eppley Laboratory, Inc.).

III. Results and Discussion

The thermogalvanic cell Cu copper formate Cu has a positive hot electrode (cathode) and positive values of the thermoelectric power (ΔE/ΔT)_{I=O}.
From data obtained in U tube cells, the thermoelectric power'of this system was measured **as a** function of copper formate concentration, free formate
concentration, free formic acid concentration, pH, and temperature range ($\Delta T = 20 - 70^{\circ}\text{C}$), as well as the discharge characterisitcs of these cells. In going from 0.11 M concentration of $Cu(HCO₂)₂·4H₂O$ to 0.35 M, the thermoelectric power increases from 0.62 to 1.25 mV/degree, for an added formic acid concentration of 0.16 M, and a $\Delta T = 45^{\circ}C$.

The species distribution-in copper formate 19 solutions was determined by Tedesco and Quintana , in ionic strength 1, perchloric medium, formic acid concentration $0 - 0.7$ M, using potentiometric and polarographic methods. The formation constants are: Bj(Cu(HCO₂)⁺) = 14; B₂ (Cu(HCO₂)₂) = 30; and
B₃ (Cu(HCO₂)3) = 82. Spectrophotometric data²⁰ at
26ºC, in a medium of ionic strength of 3 (adjusted with KNO3), and constant free formic acid concentration of 0.1 M are: β_1 (Cu(HCO₂)⁺) = 50, β_2 (Cu $(HCO_2)_2$) = 102, and β_3 (Cu(HCO₂)₃-) = 192. No data are available at higher temperatures. The differences fn the conditions employed and methods, justify the differences in equflfbrfum constants. Utilizing the data abovel9, the copper formate solutions above contain at 250c, all three copper
formate complexes and a smaller amount of the aquo-
complex. Increased total formate concentration, as sodium formate, favors the formation of $Cu(HCO₂)$ 3 (30, 50 and 65% respectively in going from 0.44 to 0.88 to 1.18 M added NaHCO₂, to a 0.35 M Cu(HCOz)2·4H20 solution, and the pH increases from 3.90 to 4.23 to 4.35). Under those conditions the thennoelectric power decreases slightly: 1.25 to 1.20 to 1.00 mV/degree ($\Delta T = 45^{\circ}$ C). At higher temperatures ft fs likely that the formate complex species will undergo dissociation, and that aquocopper complexes are present to a larger extent.

The thermoelectric power appears to be a function of the free formic acid concentration. For solutions containing 0.35 M Cu(HCO₂)₂.4H₂0, and 'IIQ.35 M NaHC02, (and approximately tfie same distrfbution of copper species and free formate) the thermoelectric power increases from 1.25 to 1.65 mV /degree ($\Delta T = 45^{\circ}$ C) as the free formic acid concentration decreases from 0.50 to 0.30 M. The thermoelectric power generally increases with in c reased ΔT . For instance, for the solution above with free formic concentration of 0.50 M the thermoelectric power increases from 1.48 to 1.58 to 1.79 to 1.86 mV/degree for ΔT of 30, 40, 50 and 60^oC respectively.

--

The concentration of copper fonnate of 0.35 M was chosen as upper concentration limit for being close, but less than the solubility at the low temperature half cell (10 - 20^oC).

The data above were obtained by cleaning the electrodes in $10-20\%$ v/v HNO₃, followed or not by electrodes in 10-20% v/v HN03. followed or not by mechanical polishing. and letting the electrodes stand in solution for at least 2-3 hours in the

dark. Current-voltage curves were obtained. Reference electrodes at each half-cell indicated that
the overvoltages are generally higher at the lower temperature electrode. Both mass transfer and charge transfer seem to contribute to the observed overvoltages. These are, however, smaller than the ohmic overvoltage. The current-voltage curves were reproducible. For instance, for a 0.35 M Cu{HC02}2·4H20, 0.35 M NaHC02, and added formic ac1d of 0.08 M, the product V open circuit (Voe) times I short circuit (I_{SC}) , VocxIsc = 54.9x.181 = 9.94 µW was obtained, and after a week, V_{OCX} ISC = 53.3x.185 = 9.86 µW, for a $\Delta T = 35^{\circ}C$

Addition of sodium salts, **e.g.,** sodium tetrafluoroborate, decreases slightly the thermoelectric powers, and the power output of the systems. The resistance of the solution decreases as expected.
The investigated concentration range of NaBF₄ was 0.35 to 1.0 M.

Figure 1. (a) Voltage-current characteristics of the copper copper formate copper thermogalvanic cell as a function of the temperature differential. Electrode area: 4.5 cm^2 ; Cell length = 5,0 cm. (b) Power output vs. voltage of the copperlcopper formatelcopper thermogalvanic cell, Total copper concentration: 1.13 M; $pH = 3.6$ (200C). Only representative points shown.

5

A more·practical cell was built with a PVC tube (2.5 cm diameter). 5 cm length, and filled up with a solution 0.35 M Cu(HCO₂)₂·4H₂0, 0.35 M NaHCO₂, and 0.08 M added form c acid. The area of
the copper electrodes was 4.5 ± 0.5 cm². The above Figure la shows the voltage-current characteristics of this cell for three temperature differentials. From the curves in Figure 1a, one can con-
clude that charge and mass transfer are important in this system. in addition to ohmic activation. responsible for the major power losses $(R (AT = 0))$ \sim 90 ohms). The resistance decreases with in-
creased ΔT ($\Delta T = 60^{\circ}C_5$, R ~60 ohms). These cells are very inexpensive. \$0.15 is the cost of the chemicals, except for the copper electrodes, which detennine the overall cost of the cell. These .aqueous cells are much less expensive than the equivalent solid state thennoelectric devices to date. Estimated maximum power density for $\Delta T =$ 60°c is about 20µW/cm'. The **above** Figure lb illustrates the power outputs of the cell as a function of the voltage.

Smaller cells (2.5 and 1.25 cm length) were also built and tested in a variety of solutions. For copper formate solutions containing 1 M NaBF4. at $\Delta T = 40^{\circ}$ C. 2.5 cm cells gave a maximum power of the length the power output of 10 μ W was obtained, suggesting that for these solutions the temperature grgdients may not have been maintained. For AT= 50 c. cells 1.25 cm long gave **9.5 µW** with 0.35 M NaBF4. By comparison, the same cell filled with CuS04(0.35 M) gave 3.3 **µW** (AT Q 5o⁰ c}. whereas twice the length **gave** 5.8 µW. The addition of sulfuric acid (20% v/v) increased the power by a factor of 2. The optimum length for these systems is between 2.5 **and 5** cm.

These cells are bejng employed to investigate comparatively the power outputs of the thennogal- vanic cells types (1) to (3). Type (3) is being investigated on graphite electrodes. The efficiency of these devices under load is being measured. These data will allow us to analyze the feasibility of the coupling of these inexpensive feasibility of the coupling of these inexpensive devices to convert.free low grade heat into electricity.

Case¹⁹ suggested that copper electrodes in copper formate solutions form a layer of Cu₂O. the semiconductor electrode. This red layer is fonned upon standing or by potentfostatic or 9alvanostatt methods. A solution 0.35 M in Cu(HCO₂)₂·4H₂O,
0.35 M in NaHCO₂, and approximately 0.2 M in added 0.35 M in NaHCO₂, and approximately 0.2 M in added formic acid was placed in the U tube cell, with a $\Delta T = 30^{\circ}C$. The copper electrodes were plates 4 x 0.5 x 0.1 cm., immersed in the solution for 2 days, after which **a** red unifonn coating of Cu20 was formed. Figure 2 shows a· comparison of the voltage current curves for a $\Delta T = 30\frac{6}{3}$ in the dark, and upon tlluminatfonb (45 µW/cm2) of one of the faces of the anode (the cold electrode). Upon illumina-
tion a photovoltage is added to the thermovoltage. The photovoltage slowly but continuously decays.
The power output upon illumination practically doubles. The photoeffect observed is an electrochemical photovoltaic effect, since it is not present when pure copper electrodes are illuminated. In order to restore light sensitivity of the illuminated electrode. ft has to be reduced 1n the dark. This effect ts being tnvesttgated. Surface analyses are being employed to characterize the

. nature of the electrodes in the **dark** and after illumination in these cells.

FIGURE 2. Voltage-current characteristtics of the copperlcopper formatelcopper thennogalvanic cell (a) in the dark; (b) with the cold anode illumi-
nated at 45 W/cm^2 . Total copper concentration: 0.35 M; total formate concentration: 1.25; pH: $3.7(20^0C)$. Only representative points shown.

IV. Conclusion

The copper|copper formate|copper system was
investigated. Practical thermoelectric powers, investigated. Practical thermoelectric powers. (AE/AT)J•O of 1.25 *to* 1.9 mV/degree. can be obtained in this system. depending on the copper fonnate. free formic acid concentration. as well as on the temperature difference between the cold and hot half-cells. These powers are higher than those obtained 1n other copper salt systems. and in other systems as well (see Table I).

Current-voltage curves indicate that in addition to ohmic drop. activation and concentration overpotentials limit the power output of these devices.

Practical cells were built and m
outputs of about 20 μ W/cm² estimated. Practical cells were built and maximum power

6

The coupling of the thermogalvanic with an
electrochemical photovoltaic effect, the photothermogalvanic cell, was shown for the first time in this system.

Acknowledgements

Helpful discussions with Ors. D. Benson, J. Christie, **A. Nozik, P.** Russell, J. Trefny, and J. Turner are gratefully **acknowledged.**

References

- 1. A.J. deBethune, T.S. Licht, and N. Swendeman,
"The temperature co-efficients of electrode poaThe temperature co-efficients of electrode po-
tentials," J. Electrochem. Soc., <u>106</u>, 616-625 (1959) . A.J. deBethune and H.O. \overline{DaT} ey, Jr., aThe thermal temperature coefficient of the calomel electrode between 0⁰ and 70ºC, II and III." J. Electrochem. Soc., <u>116</u>, 1395–1401, 1401–1406
(1969).
- 2. A.J. deBethune, "Irreversible thermodynamics in electrochemistry," J. Electrochem. Soc., 107, 829-842 (1960).
- 3. J.·N. **Agar,** "Thermogalvanic cells.'' in Advances in Electrochemistry and Electrochemical Engin-
eering". P. Delahay and C.W. Tobias, eds., vol. 3, Interscience p. 31-121 (1963).
- 4. C. Wagner, "Thermoelectric power of cells with ionic compounds involving ionic and electronic conduction.'' Progr. Solid State Chem •• *z..* 1-37 (1972).
- 5. R. Zito, Jr., "Thermogalvanic energy conversion",
AIAA J., <u>1</u>, 2133-2138 (1963).
- 6. **N.** Fuschfllo, "Thermoelectric figure of merit," in Thermoelectric Materials and Devices, I.B. Cadoff and E. Miller, eds., Reinhold Publishing
Corp., New York, (1960) pp. 31-46.
- 7. K.s/ Pitzer, "Thermodynamics of thermocells with fused or solid electrolytes," J. Phys. Chem., 65, 147-150 (1961).
- 8. M. Telkes, "Solar thermoelectric generators," J. Appl. Phys., 25, 765-777 (1954).
- 9. T. Wartanowicz, "A theoretical analysis of **a** molten salt thermocell as a thermoelectric gen- erator," Advan. Energy Conversion, 4, 149-158 (1964) .
- 10. See examples in H.L. Chum and R.A. Osteryoung,
"Thermally Regenerative Electrochemical Systems" SERI Report TR-332-416 {1980).
- 11. S. Senderoff, "Thermocell," U.S. Patent 3,294, 585 (1966) S. Senderoff. "Thermocell battery," U.S. **Patent** 3.311,506 (1967).
- 12. J.L. Weininger, "Thermogalvanic cells with silver todfde as **a** solid electrolyte," J. Electrochem. Soc., <u>111</u>, 769-74 (1964). J.L. Weininger,
"Solid electroTyte thermocell," U.S. Patent 2, 890,259 (1959). J.L. Weininger, "Non-isottennal voltaic cell having todfne electrodes," U.S. Patent 3,297,486 (1967).
- 13. B.H. Clampitt and D.E. German, "Electrochemical cell for conversion of heat energy," U.S. Patent 3,253,955 (1966).
- 14. **a. B.W.** Burrows, "Redox thennogalvanfc cells for direct energy conversion," Proc. 10th Intersociety Energy Conversion Engineering Conference, (1975) pp. 821-7.

b. B. Burrows, "Discharge **behavior** of **redox** Thermogalvanic cells." J. Electrochem. Soc.,
123, 154-9 (1976).

- 15. P.O. Miller, **A.B.** Tripler, Jr., and J.J. Ward, "The application of irreversible thermodynamics to the thermogalvanic behavior of copper-copper
sulfate systems," J. Electrochem. Soc., 113, 746-9 (1966).
- 16. G. Hoffmann and A. David, "Investigations of some electrolyte thennopiles," Acta Chim. (Budapest), 78, 373-85 (1973).
- 17. T.W. Case;' "A cuprous oxide photochemical cell.'' Trans. Electrochem. Soc., 31, 351-64 (1917).
- 18. T.S. Jayadev, "A self-regenerating semiconductor-electrolyte solar cell", unpublished results.
- 19. P.H. Tedesco and J.A.G. Quintana, "Formiatos de cobre y niquel en polucton acuosa", An. Soc. Cient. Argent., 196, 55-61 (1973).
- 20. H.G. Osawa and L.N. Dhoot, "Spectrophotometric
study of copper-formate complexes", Z. Phys.
Chem., Leipzig, 256, 841-3 (1975) (and references therein).